

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = 10V	Steady State	T _C = +25°C T _C = +100°C	ID	20 13	А
Maximum Body Diode Forward Current (Note 6)			Is	4	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I _{DM}	30	А
Avalanche Current (Note 7)			I _{AS}	14.2	A
Avalanche Energy (Note 7)			E _{AS}	10	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Tatal Bawar Dissinction (Note 6)	$T_{C} = +25^{\circ}C$	D	42	W
Total Power Dissipation (Note 6)	$T_{C} = +100^{\circ}C$	P _D	17	
Thermal Resistance, Junction to Ambient (Note 6)	R _{0JA}	44	°C/W	
Thermal Resistance, Junction to Case (Note 6)	R _{θJC}	3		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

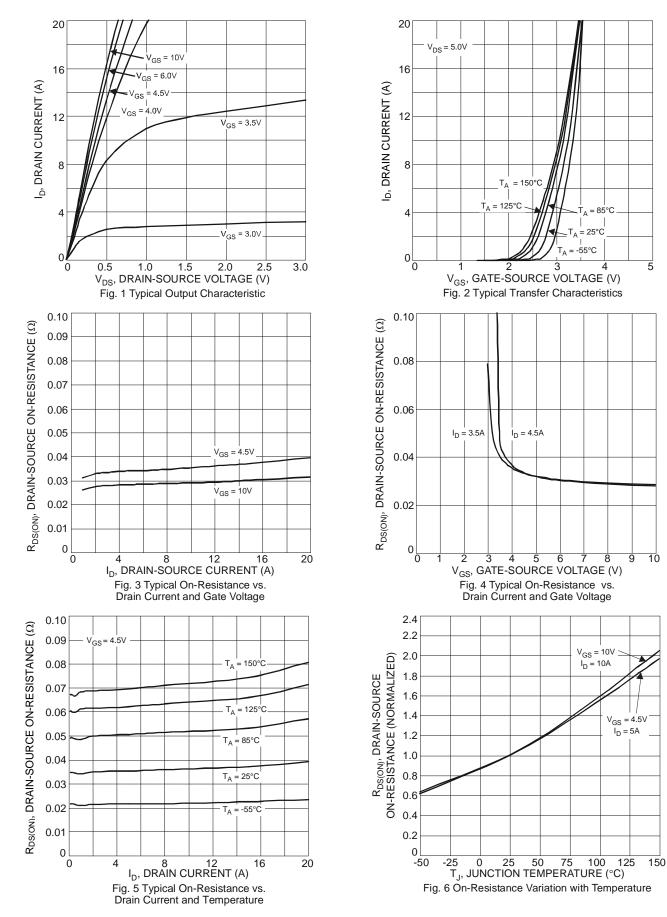
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	•,•		- 71-	1	1	
Drain-Source Breakdown Voltage	BV _{DSS}	60			V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current	I _{DSS}			1	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_		±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	1		3	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
Static Drain-Source On-Resistance	Б	_	30	40	- mΩ	$V_{GS} = 10V, I_D = 20A$
	R _{DS(ON)}	_	35	58	mΩ	$V_{GS} = 4.5V, I_D = 12A$
Diode Forward Voltage	V _{SD}	_	0.7	1.2	V	$V_{GS} = 0V, I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss		1,287			$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz
Output Capacitance	Coss	—	57	—	pF	
Reverse Transfer Capacitance	C _{rss}	_	44	—		
Gate Resistance	R _G	_	1.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge (V _{GS} = 10V)	Qg	_	22.4	_		V _{DS} = 30V, I _D = 4.3A
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	10.4	—	nC	
Gate-Source Charge	Q _{gs}	_	4.9	_	nc	
Gate-Drain Charge	Q _{gd}	_	3.0	_		
Turn-On Delay Time	t _{D(ON)}	_	6.6	_		$V_{GS} = 10V, V_{DD} = 30V, R_G = 6\Omega,$ $I_D = 4.3A$
Turn-On Rise Time	t _R	_	8.1	_		
Turn-Off Delay Time	t _{D(OFF)}		20.1		ns	
Turn-Off Fall Time	tF		4.0			
Body Diode Reverse Recovery Time	t _{RR}		18		ns	I _S = 4.3A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}		11.9		nC	I _S = 4.3A, dl/dt = 100A/µs

6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper pad layout. 7. UIS in production with L = 0.1mH, T_J = +25°C. Notes:

8. Short duration pulse test used to minimize self-heating effect.

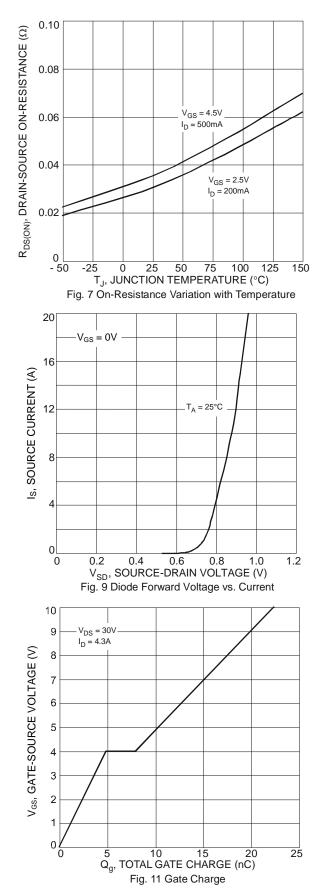
9. Guaranteed by design. Not subject to product testing.

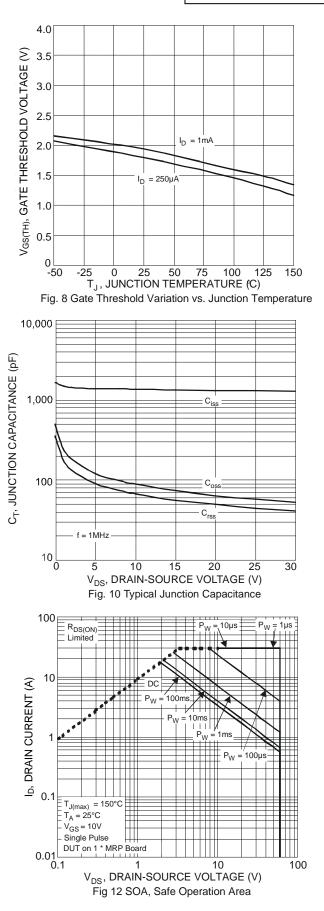




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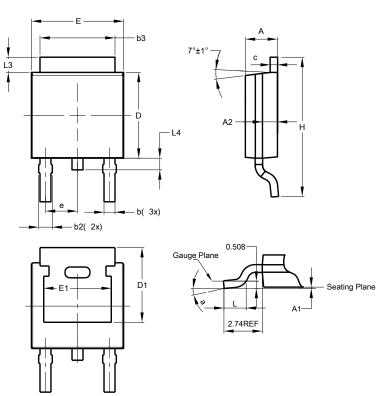


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Package Outline Dimensions

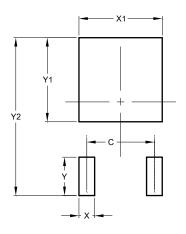
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	TO252 (DPAK)						
Dim	Min	Max	Тур				
Α	2.19	2.39	2.29				
A1	0.00	0.13	0.08				
A2	0.97	1.17	1.07				
b	0.64	0.88	0.783				
b2	0.76	1.14	0.95				
b3	5.21	5.46	5.33				
С	0.45	0.58	0.531				
D	6.00	6.20	6.10				
D1	5.21	-	-				
е	-	-	2.286				
E	6.45	6.70	6.58				
E1	4.32	-	-				
H	9.40	10.41	9.91				
L	1.40	1.78	1.59				
L3	0.88	1.27	1.08				
L4	0.64	1.02	0.83				
а	0°	10°	-				
All Dimensions in mm							

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)

Dimensions	Value (in mm)			
С	4.572			
Х	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			

TO252 (DPAK)



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